

Vishay General Semiconductor

Surface Mount PAR® Transient Voltage Suppressors

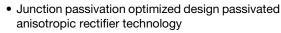
High Temperature Stability and High Reliability Conditions



DO-218 Compatible

| PRIMARY CHARACTERISTICS | | | | | |
|-----------------------------------|------------------|--|--|--|--|
| V_{BR} | 11.1 V to 52.8 V | | | | |
| P _{PPM} (10 x 1000 μs) | 6600 W | | | | |
| P _{PPM} (10 x 10 000 μs) | 5200 W | | | | |
| P_{D} | 8 W | | | | |
| V_{WM} | 10 V to 43 V | | | | |
| I _{FSM} | 700 A | | | | |
| T _J max. | 175 °C | | | | |
| Polarity | Uni-directional | | | | |
| Package | DO-218AC | | | | |

FEATURES





 T_J = 175 °C capability suitable for high reliability and automotive requirement

(e3)

· Available in uni-directional polarity only

- Available in uni-directional polarity only
- Low leakage current
- Low forward voltage drop
- High surge capability
- Meets ISO7637-2 surge specification (varied by test condition)
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C
- AEC-Q101 qualified
 - Automotive ordering code: base P/NHE3
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

TYPICAL APPLICATIONS

Use in sensitive electronics protection against voltage transients induced by inductive load switching and lighting, especially for automotive load dump protection application.

MECHANICAL DATA

Case: DO-218AC

Molding compound meets UL 94 V-0 flammability rating Base P/NHE3 - RoHS-compliant, AEC-Q101 qualified

Terminals: matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

HE3 suffix meets JESD 201 class 2 whisker test

Polarity: heatsink is anode

| MAXIMUM RATINGS (T _C = 25 °C unless otherwise noted) | | | | | | |
|---|-----------------------------------|------------------|------|----|--|--|
| PARAMETER | SYMBOL | VALUE | UNIT | | | |
| Deale and a manual discipation | with 10/1000 μs waveform | D | 6600 | w | | |
| Peak pulse power dissipation | with 10/10 000 µs waveform | P _{PPM} | 5200 | VV | | |
| Power dissipation on infinite heats | P _D | 8.0 | W | | | |
| Peak pulse current with 10/1000 p | I _{PPM} ⁽¹⁾ | See next table | Α | | | |
| Peak forward surge current 8.3 m | I _{FSM} | 700 | Α | | | |
| Operating junction and storage te | T _J , T _{STG} | -55 to +175 | °C | | | |

Note

(1) Non-repetitive current pulse derated above T_A = 25 °C

SM8S10AT thru SM8S43AT

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| ELECTRICAL CHARACTERISTICS (T _C = 25 °C unless otherwise noted) | | | | | | | | | | |
|---|---|------|------|------------------------|------------------------|---|--|----------------------------------|---|---|
| DEVICE | BREAKDOWN VOLTAGE V _{BR} (V) | | | TEST CURRENT | STAND-OFF VOLTAGE | MAXIMUM REVERSE LEAKAGE | MAXIMUM REVERSE LEAKAGE | MAX. PEAK PULSE CURRENT | MAXIMUM CLAMPING VOLTAGE | TYPICAL TEMP. COEFFICIENT |
| TYPE | MIN. | NOM. | MAX. | I _T (mA) | V _{WM} (V) | AT V _{WM} I _D (μA) | AT V _{WM} T _J = 175 °C I _D (μA) | AT 10/1000 µs WAVEFORM (A) | AT I _{PPM} V _C (V) | OF V _{BR} ⁽¹⁾ αT (%/°C) |
| SM8S10AT | 11.1 | 11.7 | 12.3 | 5.0 | 10.0 | 15 | 250 | 388 | 17.0 | 0.069 |
| SM8S11AT | 12.2 | 12.9 | 13.5 | 5.0 | 11.0 | 10 | 150 | 363 | 18.2 | 0.072 |
| SM8S12AT | 13.3 | 14.0 | 14.7 | 5.0 | 12.0 | 10 | 150 | 332 | 19.9 | 0.074 |
| SM8S13AT | 14.4 | 15.2 | 15.9 | 5.0 | 13.0 | 10 | 150 | 307 | 21.5 | 0.076 |
| SM8S14AT | 15.6 | 16.4 | 17.2 | 5.0 | 14.0 | 10 | 150 | 284 | 23.2 | 0.078 |
| SM8S15AT | 16.7 | 17.6 | 18.5 | 5.0 | 15.0 | 10 | 150 | 270 | 24.4 | 0.080 |
| SM8S16AT | 17.8 | 18.8 | 19.7 | 5.0 | 16.0 | 10 | 150 | 254 | 26.0 | 0.081 |
| SM8S17AT | 18.9 | 19.9 | 20.9 | 5.0 | 17.0 | 10 | 150 | 239 | 27.6 | 0.082 |
| SM8S18AT | 20.0 | 21.1 | 22.1 | 5.0 | 18.0 | 10 | 150 | 226 | 29.2 | 0.083 |
| SM8S20AT | 22.2 | 23.4 | 24.5 | 5.0 | 20.0 | 10 | 150 | 204 | 32.4 | 0.085 |
| SM8S22AT | 24.4 | 25.7 | 26.9 | 5.0 | 22.0 | 10 | 150 | 186 | 35.5 | 0.086 |
| SM8S24AT | 26.7 | 28.1 | 29.5 | 5.0 | 24.0 | 10 | 150 | 170 | 38.9 | 0.087 |
| SM8S26AT | 28.9 | 30.4 | 31.9 | 5.0 | 26.0 | 10 | 150 | 157 | 42.1 | 0.088 |
| SM8S28AT | 31.1 | 32.8 | 34.4 | 5.0 | 28.0 | 10 | 150 | 145 | 45.4 | 0.089 |
| SM8S30AT | 33.3 | 35.1 | 36.8 | 5.0 | 30.0 | 10 | 150 | 136 | 48.4 | 0.090 |
| SM8S33AT | 36.7 | 38.7 | 40.6 | 5.0 | 33.0 | 10 | 150 | 124 | 53.3 | 0.091 |
| SM8S36AT | 40.0 | 42.1 | 44.2 | 5.0 | 36.0 | 10 | 150 | 114 | 58.1 | 0.091 |
| SM8S40AT | 44.4 | 46.8 | 49.1 | 5.0 | 40 | 10 | 150 | 102 | 64.5 | 0.092 |
| SM8S43AT | 47.8 | 50.3 | 52.8 | 5.0 | 43 | 10 | 150 | 95.1 | 69.4 | 0.093 |

Note

To calculate V_{BR} vs. junction temperature, use the following formula: V_{BR} at $T_J = V_{BR}$ at 25 °C x (1 + αT x (T_J - 25))

| THERMAL CHARACTERISTICS (T _C = 25 °C unless otherwise noted) | | | | | |
|---|----------------|-------|------|--|--|
| PARAMETER | SYMBOL | VALUE | UNIT | | |
| Typical thermal resistance, junction to case | $R_{	heta JC}$ | 0.90 | °C/W | | |

| ORDERING INFORMATION (Example) | | | | | | | |
|--------------------------------|-----------------|------------------------|---------------|---|--|--|--|
| PREFERRED P/N | UNIT WEIGHT (g) | PREFERRED PACKAGE CODE | BASE QUANTITY | DELIVERY MODE | | | |
| SM8S10ATHE3/I (1) | 2.605 | I | 750 | 13" diameter plastic tape and reel, anode towards the sprocket hole | | | |

Note

(1) AEC-Q101 qualified

[•] For all types maximum V_F = 1.8 V at I_F = 100 A measured on 8.3 ms single half sine-wave or equivalent square wave, duty cycle = 4 pulses per minute maximum



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RATINGS AND CHARACTERISTICS CURVES (T_A = 25 °C unless otherwise noted)

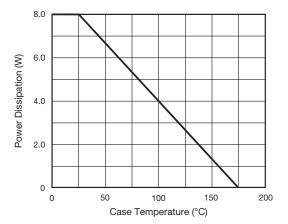


Fig. 1 - Power Derating Curve

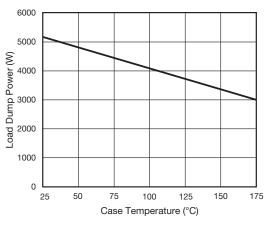


Fig. 2 - Load Dump Power Characteristics (10 ms Exponential Waveform)

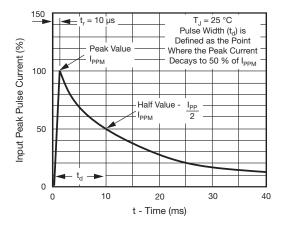


Fig. 3 - Pulse Waveform

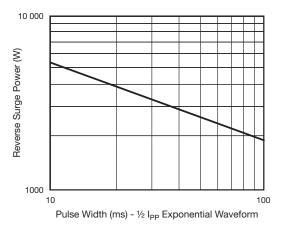


Fig. 4 - Reverse Power Capability

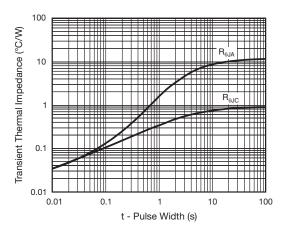


Fig. 5 - Typical Transient Thermal Impedance

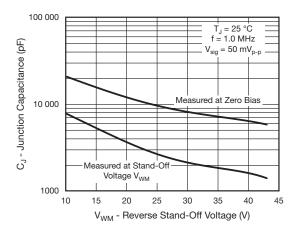


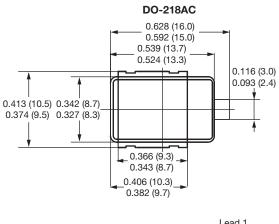
Fig. 6 - Typical Junction Capacitance

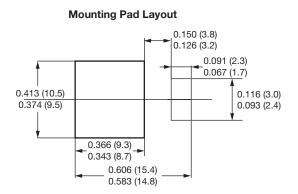


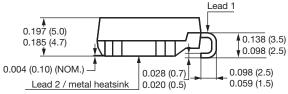


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PACKAGE OUTLINE DIMENSIONS in inches (millimeters)









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